

LTC4440-5

ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage		TS Voltage (100ms).....	–5V to 80V
V_{CC}	–0.3V to 15V	Peak Output Current < 1 μ s (TG)	4A
BOOST – TS	–0.3V to 15V	Operating Ambient Temperature Range	
INP Voltage	–0.3V to 15V	(Note 2)	–40°C to 85°C
BOOST Voltage (Continuous)	–0.3V to 85V	Junction Temperature (Note 3)	125°C
BOOST Voltage (100ms)	–0.3V to 95V	Storage Temperature Range	–65°C to 150°C
TS Voltage (Continuous)	–5V to 70V	Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

<p>TOP VIEW</p> <p>MS8E PACKAGE 8-LEAD PLASTIC MSOP $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 40^{\circ}\text{C/W}$ (NOTE 4) EXPOSED PAD IS GND (PIN 9), MUST BE SOLDERED TO PCB</p>		<p>TOP VIEW</p> <p>S6 PACKAGE 6-LEAD PLASTIC SOT-23 $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 230^{\circ}\text{C/W}$</p>	
ORDER PART NUMBER	MS8E PART MARKING	ORDER PART NUMBER	S6 PART MARKING
LTC4440EMS8E-5	LTBRG	LTC4440ES6-5	LTBRF
<p>Order Options Tape and Reel: Add #TR Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF Lead Free Part Marking: http://www.linear.com/leadfree/</p>			

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_{CC} = V_{BOOST} = 6\text{V}$, $V_{TS} = \text{GND} = 0\text{V}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Main Supply (V_{CC})						
I_{VCC}	DC Supply Current Normal Operation UVLO	INP = 0V $V_{CC} < \text{UVLO Threshold (Falling)} - 0.1\text{V}$		200 18	325 40	μA μA
UVLO	Undervoltage Lockout Threshold	V_{CC} Rising V_{CC} Falling Hysteresis	● 2.75 ● 2.60	3.20 3.04	3.65 3.50	V V mV
Bootstrapped Supply (BOOST – TS)						
I_{BOOST}	DC Supply Current Normal Operation	INP = 0V INP = 6V		0 310	450	μA μA
Input Signal (INP)						
V_{IH}	High Input Threshold	INP Ramping High	● 1.2	1.6	2	V
V_{IL}	Low Input Threshold	INP Ramping Low	● 0.8	1.25	1.6	V
$V_{IH} - V_{IL}$	Input Voltage Hysteresis			0.350		V
I_{INP}	Input Pin Bias Current			± 0.01	± 2	μA

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ELECTRICAL CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Output Gate Driver (TG)						
V_{OH}	High Output Voltage	$I_{TG} = -10\text{mA}$, $V_{OH} = V_{\text{BOOST}} - V_{TG}$		0.7		V
V_{OL}	Low Output Voltage	$I_{TG} = 100\text{mA}$	●	185	275	mV
I_{PU}	Peak Pull-Up Current		●	0.75	1.1	A
R_{DS}	Output Pull-Down Resistance		●	1.85	2.75	Ω
Switching Timing						
t_r	Output Rise Time	10% – 90%, $C_L = 1\text{nF}$ 10% – 90%, $C_L = 10\text{nF}$		10 100		ns ns
t_f	Output Fall Time	10% – 90%, $C_L = 1\text{nF}$ 10% – 90%, $C_L = 10\text{nF}$		7 70		ns ns
t_{PLH}	Output Low-High Propagation Delay		●	35	65	ns
t_{PHL}	Output High-Low Propagation Delay		●	33	65	ns

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

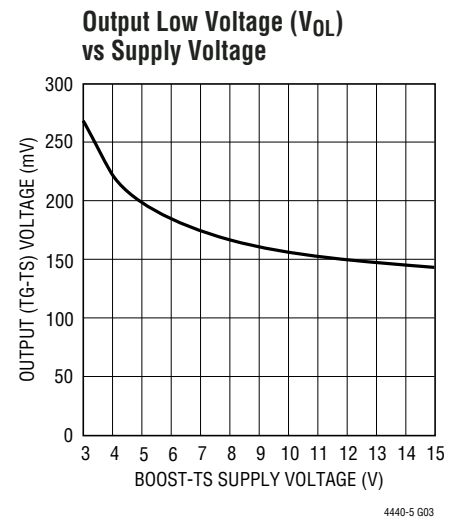
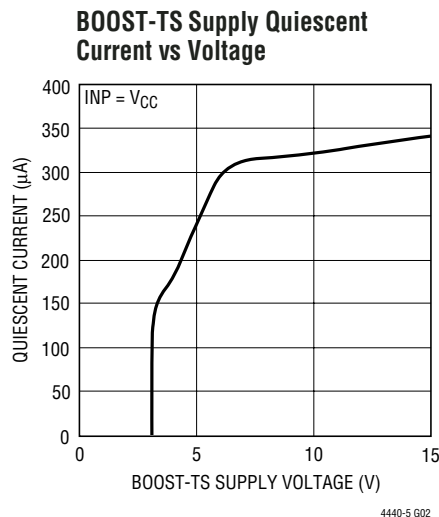
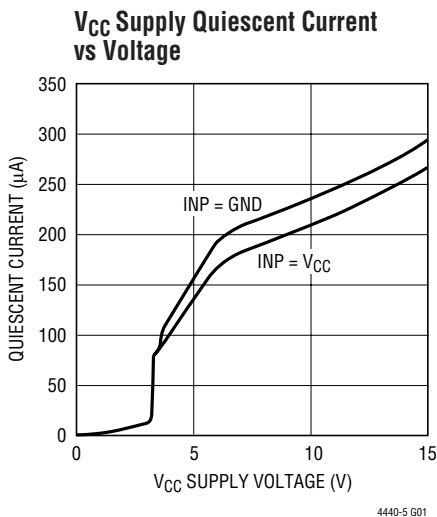
Note 2: The LTC4440-5 is guaranteed to meet performance specifications from 0°C to 85°C . Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: T_J is calculated from the ambient temperature T_A and power dissipation PD according to the following formula:

$$T_J = T_A + (PD \cdot \theta_{JA}^\circ\text{C/W})$$

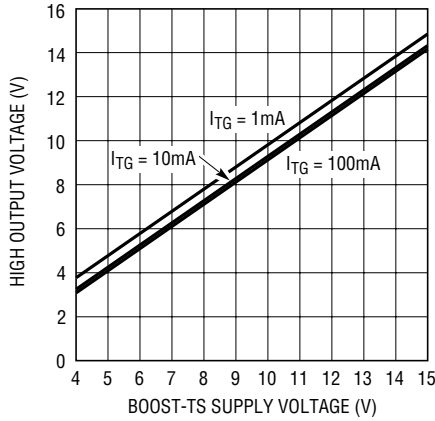
Note 4: Failure to solder the exposed back side of the MS8E package to the PC board will result in a thermal resistance much higher than 40°C/W .

TYPICAL PERFORMANCE CHARACTERISTICS

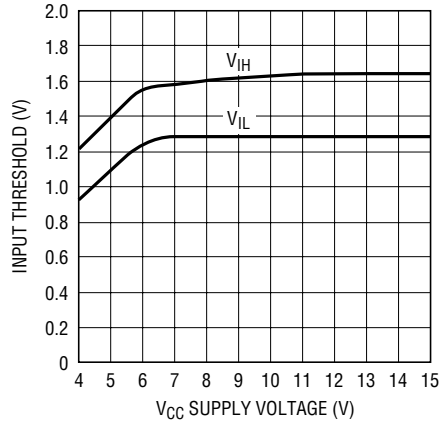


TYPICAL PERFORMANCE CHARACTERISTICS

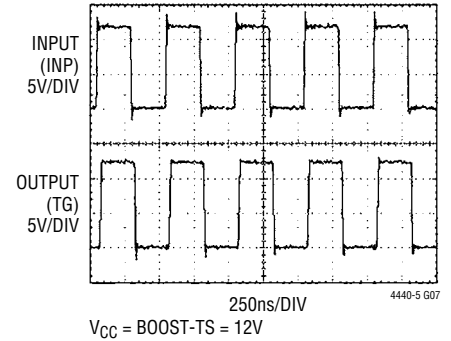
Output High Voltage (V_{OH}) vs Supply Voltage



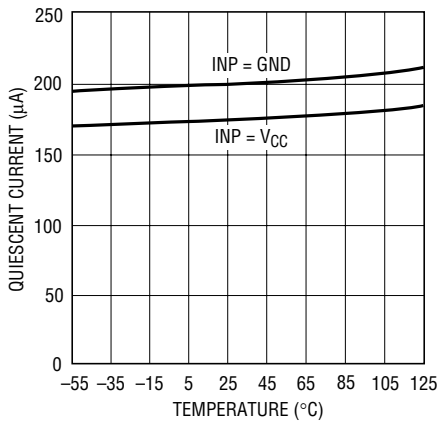
Input (INP) Thresholds vs Supply Voltage



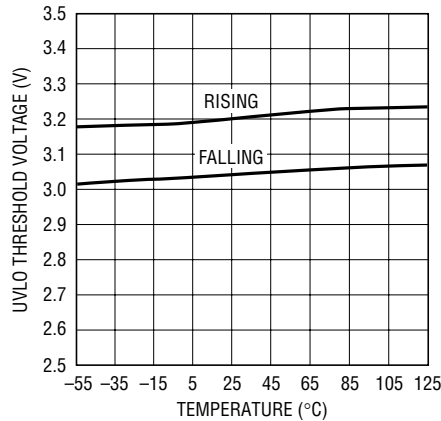
2MHz Operation



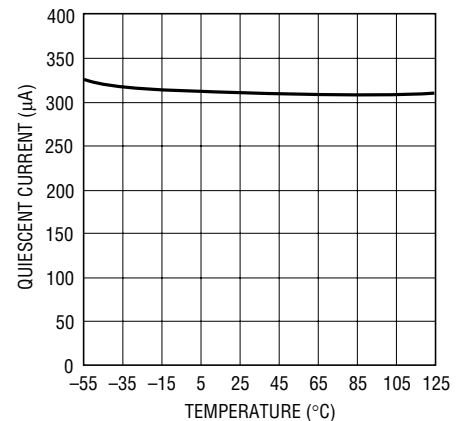
V_{CC} Supply Current vs Temperature



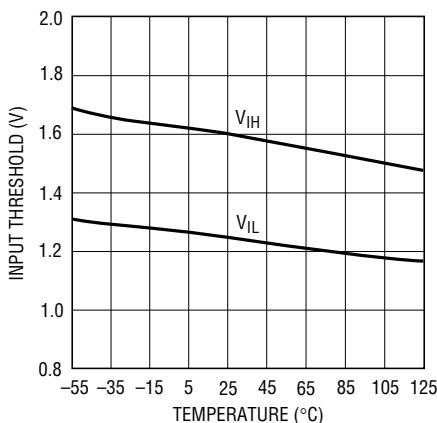
V_{CC} Undervoltage Lockout Thresholds vs Temperature



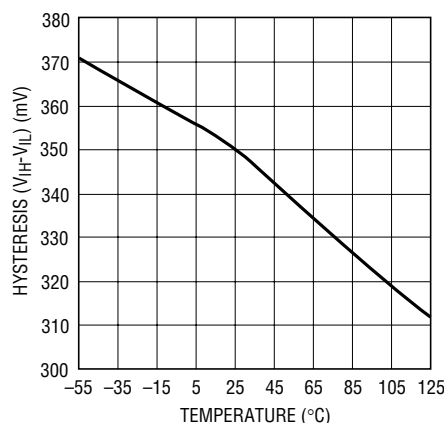
BOOST-TS Quiescent Current vs Temperature



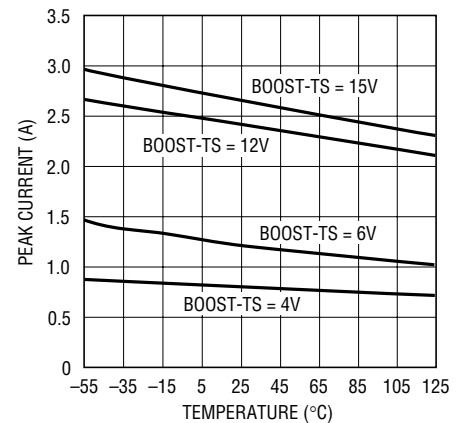
Input (INP) Threshold vs Temperature



Input Threshold Hysteresis vs Temperature

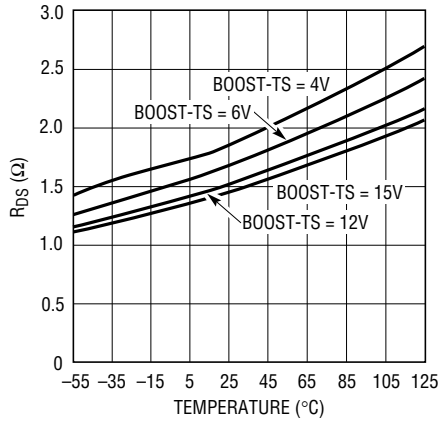


Peak Driver (TG) Pull-Up Current vs Temperature

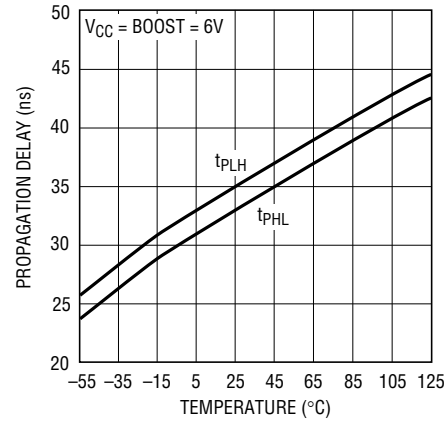


TYPICAL PERFORMANCE CHARACTERISTICS

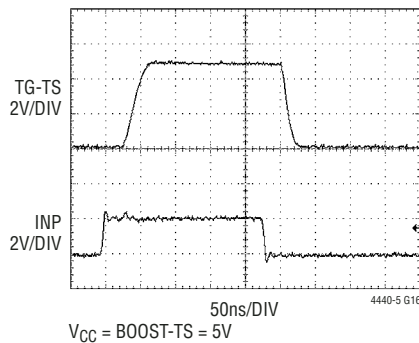
Output Driver Pull-Down
Resistance vs Temperature



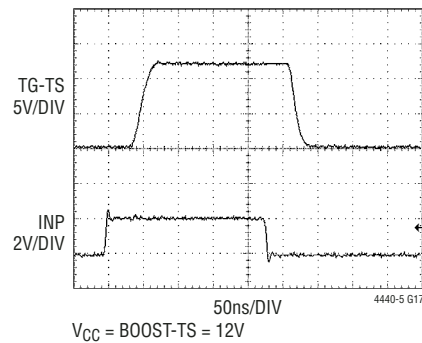
Propagation Delay vs Temperature



Driving a 3300pF Capacitive Load



Driving a 3300pF Capacitive Load



PIN FUNCTIONS

SOT-23 Package

V_{CC} (Pin 1): Chip Supply. This pin powers the internal low side circuitry. A low ESR ceramic bypass capacitor should be tied between this pin and the GND pin (Pin 2).

GND (Pin 2): Chip Ground.

INP (Pin 3): Input Signal. TTL/CMOS compatible input referenced to GND (Pin 2).

TS (Pin 4): Top (High Side) source connection or GND if used in ground referenced applications.

TG (Pin 5): High Current Gate Driver Output (Top Gate). This pin swings between TS and BOOST.

BOOST (Pin 6): High Side Bootstrapped Supply. An external capacitor should be tied between this pin and TS (Pin 4). Normally, a bootstrap diode is connected between V_{CC} (Pin 1) and this pin. Voltage swing at this pin is from V_{CC} - V_D to V_{IN} + V_{CC} - V_D, where V_D is the forward voltage drop of the bootstrap diode.

PIN FUNCTIONS

Exposed Pad MS8E Package

INP (Pin 1): Input Signal. TTL/CMOS compatible input referenced to GND (Pin 2).

GND (Pins 2, 4): Chip Ground.

V_{CC} (Pin 3): Chip Supply. This pin powers the internal low side circuitry. A low ESR ceramic bypass capacitor should be tied between this pin and the GND pin (Pin 2).

NC (Pin 5): No Connect. No connection required. For convenience, this pin may be tied to Pin 6 (BOOST) on the application board.

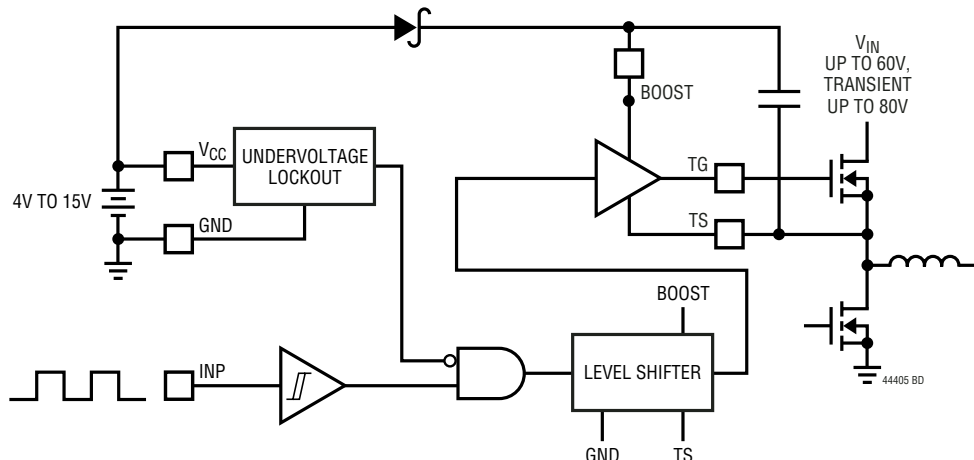
BOOST (Pin 6): High Side Bootstrapped Supply. An external capacitor should be tied between this pin and TS (Pin 8). Normally, a bootstrap diode is connected between V_{CC} (Pin 3) and this pin. Voltage swing at this pin is from V_{CC} - V_D to V_{IN} + V_{CC} - V_D, where V_D is the forward voltage drop of the bootstrap diode.

TG (Pin 7): High Current Gate Driver Output (Top Gate). This pin swings between TS and BOOST.

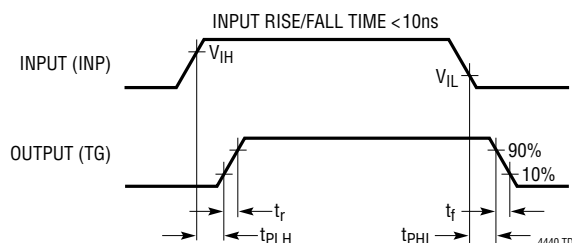
TS (Pin 8): Top (High Side) source connection or GND if used in ground referenced applications.

Exposed Pad (Pin 9): Ground. Must be electrically connected to Pins 2 and 4 and soldered to PCB ground for optimum thermal performance.

BLOCK DIAGRAM



TIMING DIAGRAM



APPLICATIONS INFORMATION

Power Dissipation

To ensure proper operation and long-term reliability, the LTC4440-5 must not operate beyond its maximum temperature rating. Package junction temperature can be calculated by:

$$T_J = T_A + PD (\theta_{JA})$$

where:

T_J = Junction Temperature

T_A = Ambient Temperature

PD = Power Dissipation

θ_{JA} = Junction-to-Ambient Thermal Resistance

Power dissipation consists of standby and switching power losses:

$$PD = P_{STDBY} + P_{AC}$$

where:

P_{STDBY} = Standby Power Losses

P_{AC} = AC Switching Losses

The LTC4440-5 consumes very little current during standby. The DC power loss at $V_{CC} = 6V$ and $V_{BOOST-TS} = 6V$ is only $(250\mu A)(5V) = 1.2mW$ with $INP = 0V$.

AC switching losses are made up of the output capacitive load losses and the transition state losses. The capacitive load losses are primarily due to the large AC currents needed to charge and discharge the load capacitance during switching. Load losses for the output driver driving a pure capacitive load C_{OUT} would be:

$$\text{Load Capacitive Power} = (C_{OUT})(f)(V_{BOOST-TS})^2$$

The power MOSFET's gate capacitance seen by the driver output varies with its V_{GS} voltage level during switching. A power MOSFET's capacitive load power dissipation can be calculated using its gate charge, Q_G . The Q_G value corresponding to the MOSFET's V_{GS} value (V_{CC} in this case) can be readily obtained from the manufacturer's Q_G vs V_{GS} curves:

$$\text{Load Capacitive Power (MOS)} = (V_{BOOST-TS})(Q_G)(f)$$

Transition state power losses are due to both AC currents required to charge and discharge the driver's internal

nodal capacitances and cross-conduction currents in the internal gates.

Undervoltage Lockout (UVLO)

The LTC4440-5 contains an undervoltage lockout detector that monitors V_{CC} . When V_{CC} falls below 3.04V, the internal buffer is disabled and the output pin TG is pulled down to TS.

Bypassing and Grounding

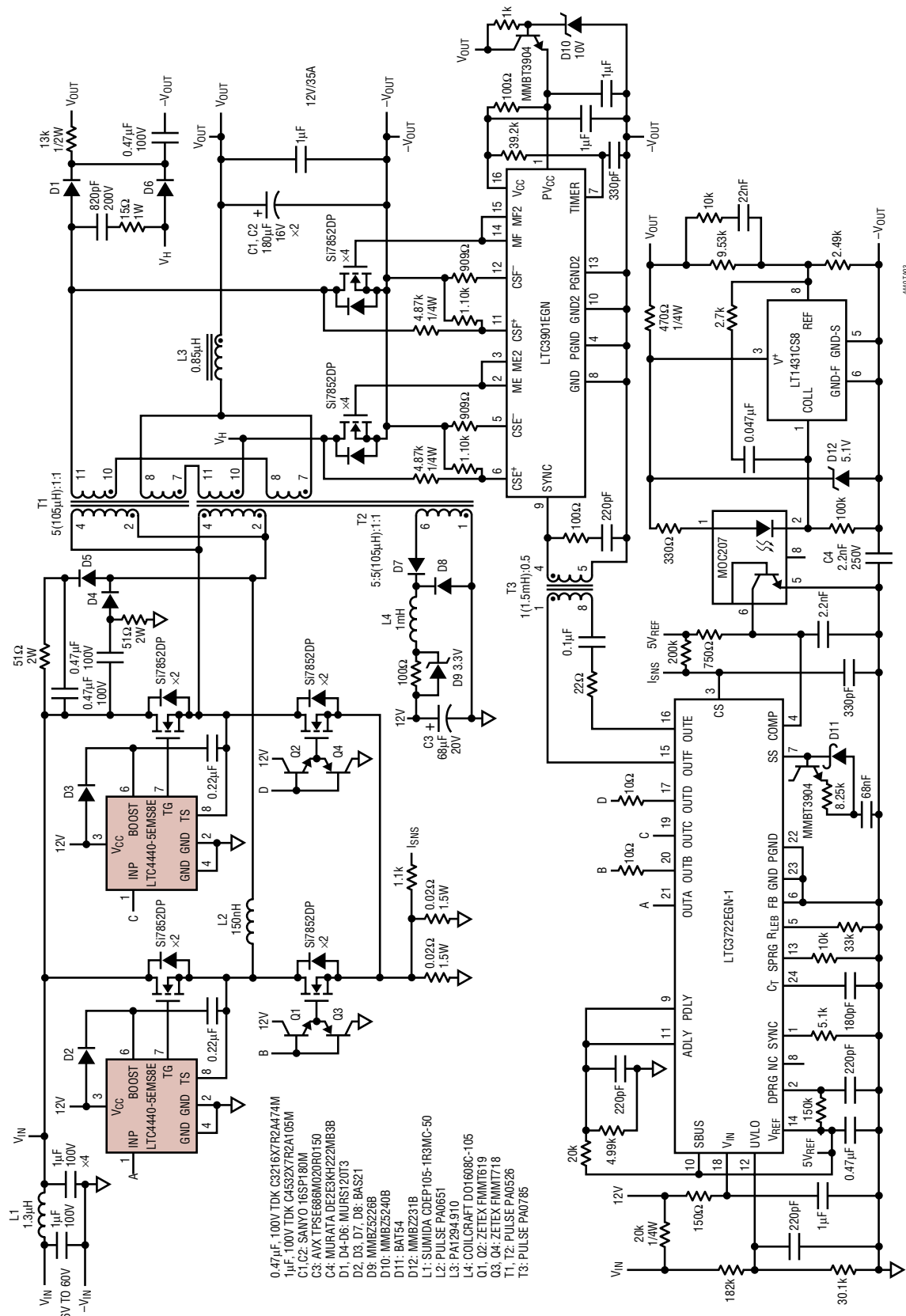
The LTC4440-5 requires proper bypassing on the V_{CC} and $V_{BOOST-TS}$ supplies due to its high speed switching (nanoseconds) and large AC currents (Amperes). Careless component placement and PCB trace routing may cause excessive ringing and under/overshoot.

To obtain the optimum performance from the LTC4440-5:

- Mount the bypass capacitors as close as possible between the V_{CC} and GND pins and the BOOST and TS pins. The leads should be shortened as much as possible to reduce lead inductance.
- Use a low inductance, low impedance ground plane to reduce any ground drop and stray capacitance. Remember that the LTC4440-5 switches >2A peak currents and any significant ground drop will degrade signal integrity.
- Plan the power/ground routing carefully. Know where the large load switching current is coming from and going to. Maintain separate ground return paths for the input pin and the output power stage.
- Keep the copper trace between the driver output pin and the load short and wide.
- When using the MS8E package, be sure to solder the exposed pad on the back side of the LTC4440-5 package to the board. Correctly soldered to a 2500mm² double-sided 1oz copper board, the LTC4440-5 has a thermal resistance of approximately 40°C/W. Failure to make good thermal contact between the exposed back side and the copper board will result in thermal resistances far greater than 40°C/W.

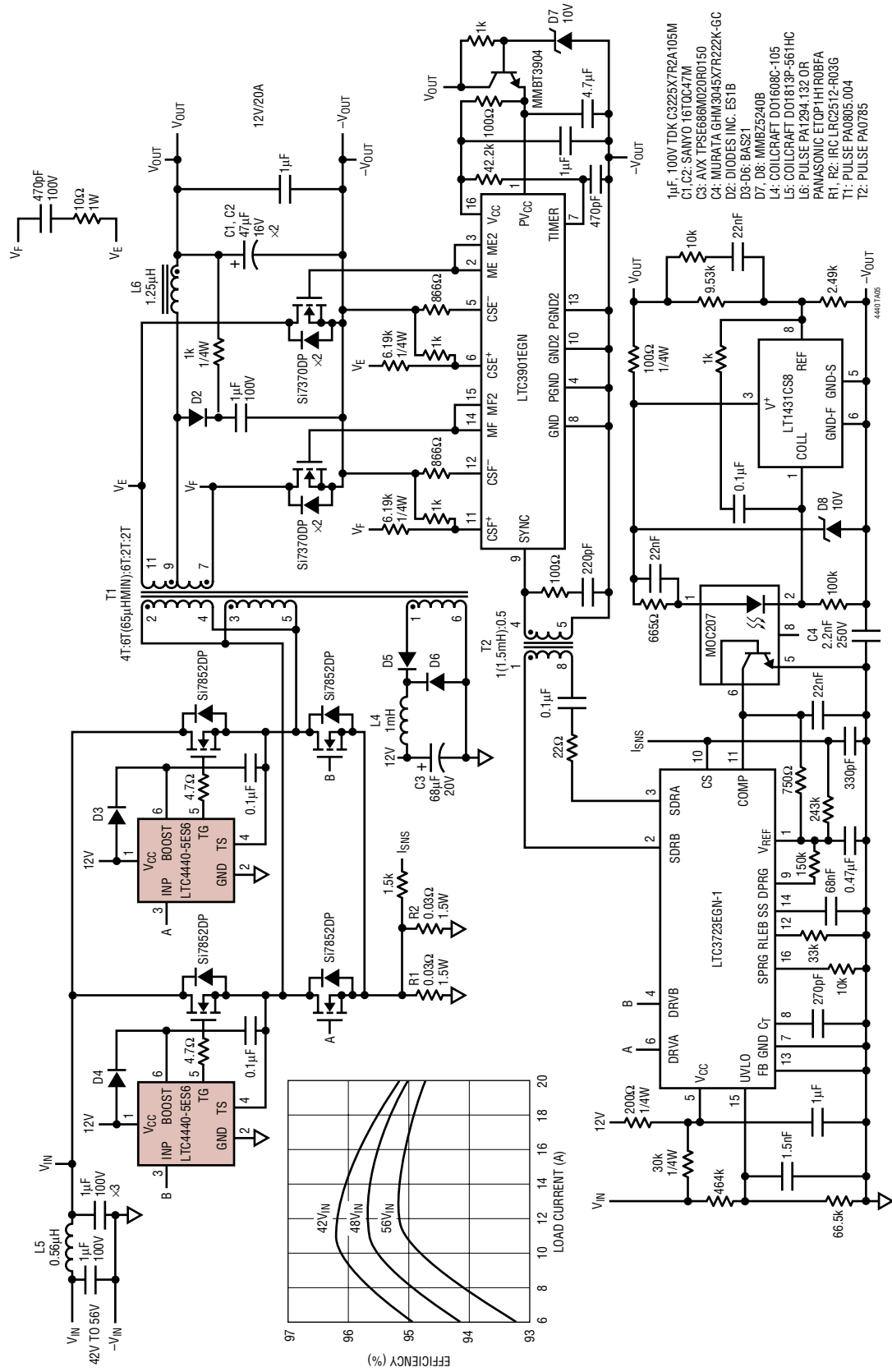
TYPICAL APPLICATIONS

LTC3722/LTC4440-5 420W 36V-60V_{IN} to 12V/35A Isolated Full-Bridge Supply



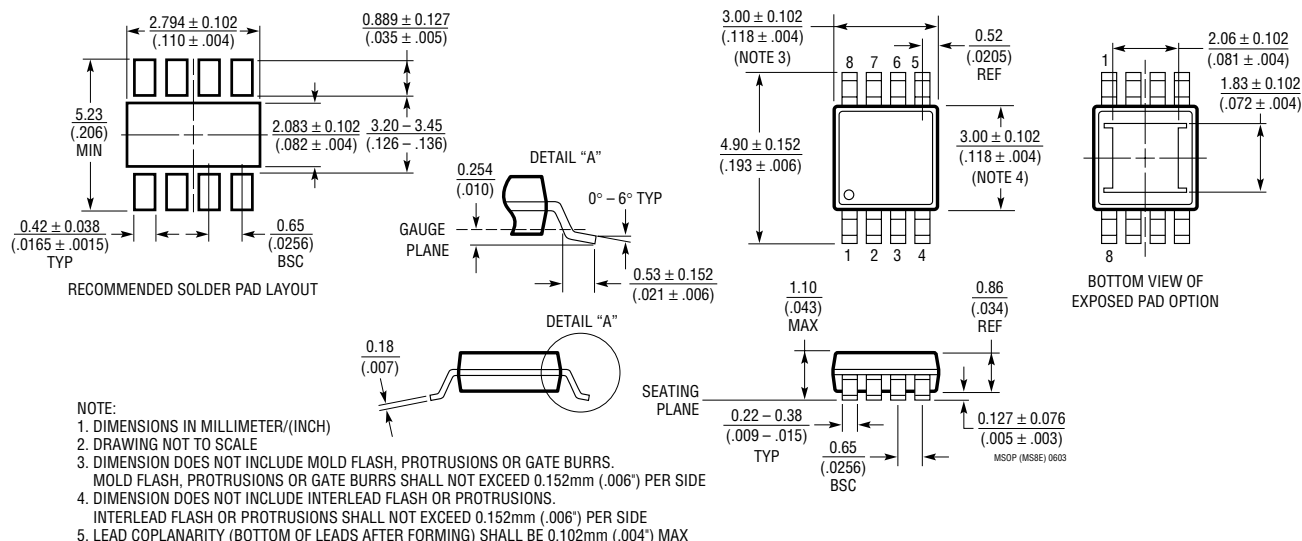
TYPICAL APPLICATIONS

LTC3723-1 240W 42-56VIN to 12V/20A Isolated 1/4Brick (2.3" × 1.45")



PACKAGE DESCRIPTION

MS8E Package 8-Lead Plastic MSOP (Reference LTC DWG # 05-08-1662)



S6 Package 6-Lead Plastic TSOT-23 (Reference LTC DWG # 05-08-1636)

